

Automotive Dual N-Channel 60 V (D-S) 175 °C MOSFET

| PRODUCT SUMMARY | | | | | |
|--|----------------|--|--|--|--|
| V _{DS} (V) | 60 | | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$ | 0.0562 | | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$ | 0.0745 | | | | |
| I _D (A) per leg | 15 | | | | |
| Configuration | Dual | | | | |
| Package | PowerPAK SO-8L | | | | |

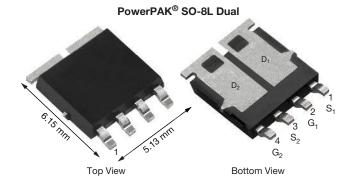
FEATURES

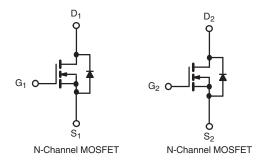
- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE





| ABSOLUTE MAXIMUM RATINGS | $T_C = 25$ °C, unless | s otherwise noted | i) | | |
|---|-------------------------|-----------------------------------|----------------------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Drain-Source Voltage | | V _{DS} | 60 | V | |
| Gate-Source Voltage | | V_{GS} | V _{GS} ± 20 | | |
| Continuous Drain Current a | T _C = 25 °C | 1 | 15 | | |
| Continuous Drain Current " | T _C = 125 °C | I _D | 10.5 | | |
| Continuous Source Current (Diode conduction) ^a | | I _S | 8 | А | |
| Pulsed Drain Current ^b | | I _{DM} | 60 | | |
| Single Pulse Avalanche Current L = 0.1 mH | | I _{AS} | 16 | | |
| Single Pulse Avalanche Energy | L=0.1111H | E _{AS} | 12 | mJ | |
| Maximum Power Dissipation ^b | T _C = 25 °C | D | 34 | W | |
| iviaximum rower Dissipation 5 | T _C = 125 °C | P_{D} | 11 | VV | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +175 | °C | |
| Soldering Recommendations (Peak temperature) d, e | | - | 260 | °C | |

| THERMAL RESISTANCE RATINGS | | | | |
|----------------------------|-------------|-------------------|-------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Junction-to-Ambient | PCB mount c | R _{thJA} | 85 | °C/W |
| Junction-to-Case (Drain) | | R _{thJC} | 4.3 | C/VV |

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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| PARAMETER | SYMBOL | TES | MIN. | TYP. | MAX. | UNIT | |
|--------------------------------------|---------------------|---|---|------|--------|--------|----|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$ | | 60 | - | - | V |
| Gate-Source Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | | 1.5 | 2.0 | 2.5 | V |
| Gate-Source Leakage | I _{GSS} | V _{DS} = | 0 V, V _{GS} = ± 20 V | - | - | ± 100 | nA |
| | | V _{GS} = 0 V | V _{DS} = 60 V | - | - | 1 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{GS} = 0 V | V _{DS} = 60 V, T _J = 125 °C | - | - | 50 | μΑ |
| | | V _{GS} = 0 V | V _{DS} = 60 V, T _J = 175 °C | - | - | 150 | |
| On-State Drain Current ^a | I _{D(on)} | V _{GS} = 10 V | $V_{DS} \ge 5 V$ | 20 | - | - | Α |
| | | V _{GS} = 10 V | I _D = 3.7 A | - | 0.0470 | 0.0562 | Ω |
| Drain Course On State Resistance 8 | В | V _{GS} = 10 V | I _D = 3.7 A, T _J = 125 °C | - | - | 0.0989 | |
| Drain-Source On-State Resistance a | R _{DS(on)} | V _{GS} = 10 V | I _D = 3.7 A, T _J = 175 °C | - | - | 0.1254 | |
| | | V _{GS} = 4.5 V | I _D = 3.3 A | - | 0.0620 | 0.0745 | |
| Forward Transconductance b | 9fs | V _{DS} | V _{DS} = 15 V, I _D = 5 A | | 11 | - | S |
| Dynamic ^b | | | | | | | |
| Input Capacitance | C _{iss} | | V _{DS} = 30 V, f = 1 MHz | - | 357 | 446 | pF |
| Output Capacitance | Coss | $V_{GS} = 0 V$ | | - | 66 | 83 | |
| Reverse Transfer Capacitance | C _{rss} | | | - | 26 | 33 | |
| Total Gate Charge c | Qg | | | - | 8.1 | 12 | |
| Gate-Source Charge c | Q _{gs} | V _{GS} = 10 V | $V_{DS} = 30 \text{ V}, I_D = 4.5 \text{ A}$ | - | 1.3 | - | nC |
| Gate-Drain Charge ^c | Q_{gd} | | | - | 1.7 | - | |
| Gate Resistance | R_g | | f = 1 MHz | | - | 7 | Ω |
| Turn-On Delay Time ^c | t _{d(on)} | | | - | 6 | 9 | |
| Rise Time ^c | t _r | $V_{DD} = 30 \text{ V, } R_L = 30 \Omega$ $I_D \cong 1 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 1 \Omega$ | | - | 6 | 9 | ns |
| Turn-Off Delay Time ^c | t _{d(off)} | | | - | 12 | 18 | |
| Fall Time ^c | t _f | 1 | - | 7 | 11 | | |
| Source-Drain Diode Ratings and Chara | acteristics b | | | | • | | |
| Pulsed Current ^a | I _{SM} | | | - | - | 60 | Α |
| Forward Voltage | V _{SD} | I _F = 2.4 A, V _{GS} = 0 V | | _ | 0.8 | 1.1 | V |

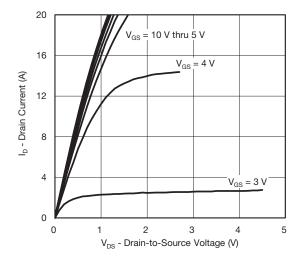
Notes

- a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

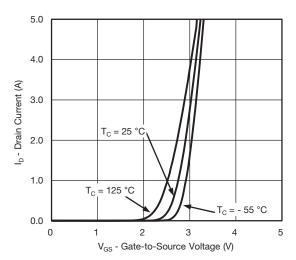
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



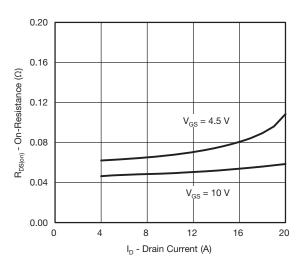
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



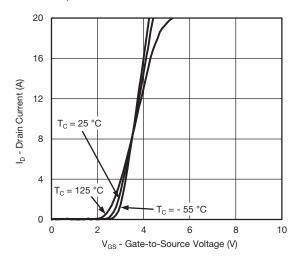
Output Characteristics



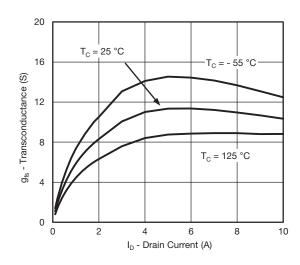
Transfer Characteristics



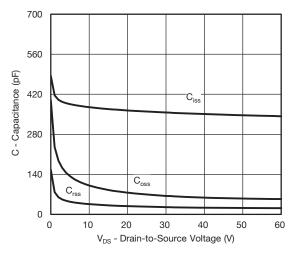
On-Resistance vs. Drain Current



Transfer Characteristics

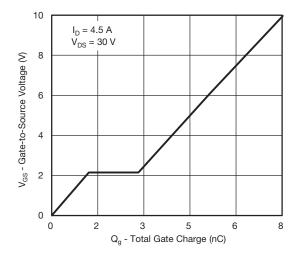


Transconductance

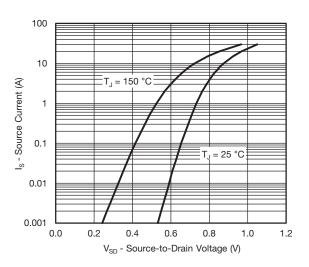




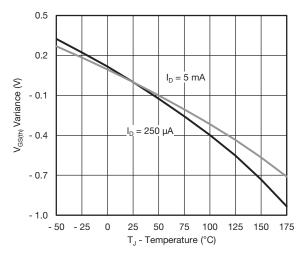
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



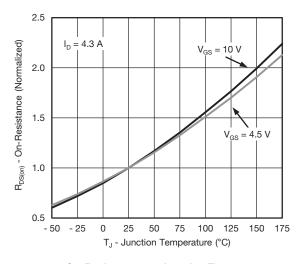
Gate Charge



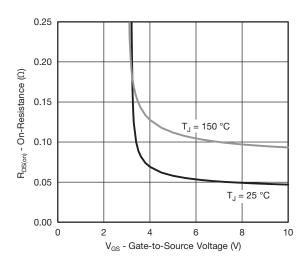
Source Drain Diode Forward Voltage



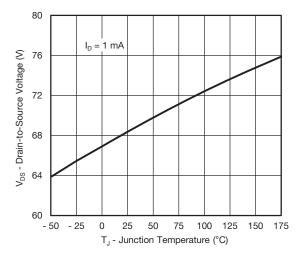
Threshold Voltage



On-Resistance vs. Junction Temperature



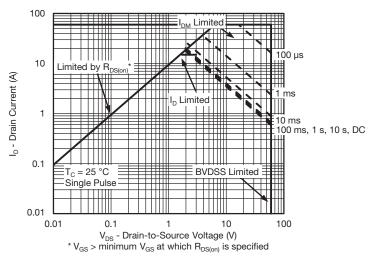
On-Resistance vs. Gate-to-Source Voltage



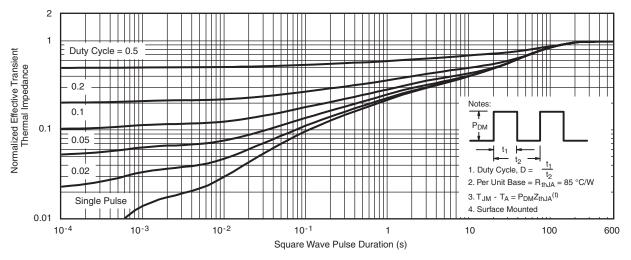
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



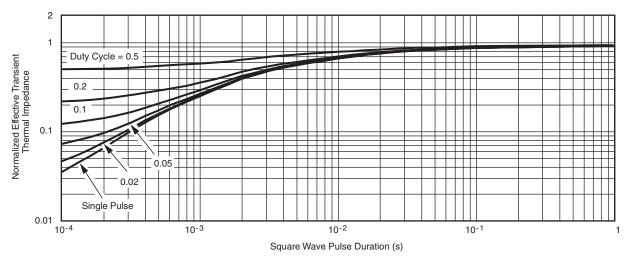
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63267.





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| REVISION | HISTORY a | | |
|----------|-----------|---|--|
| REVISION | DATE | DESCRIPTION OF CHANGE | |
| В | 04-Aug-15 | Revised R _g minimum limit | |
| С | 14-Jun-16 | Corrected I _D in product summary table | |

Note

a. As of April 2014

PowerPAK® SO-8L

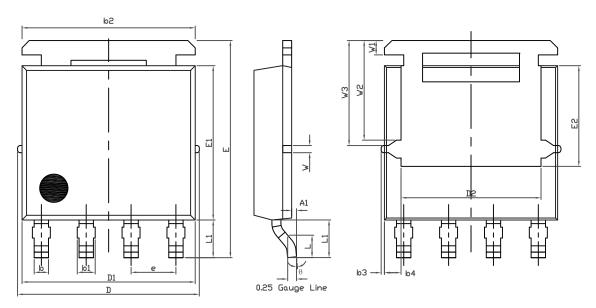
Ordering codes for the SQ rugged series power MOSFETs in the PowerPAK SO-8L package:

| DATASHEET PART NUMBER | OLD ORDERING CODE ^a | NEW ORDERING CODE |
|-----------------------|--------------------------------|-------------------|
| SQJ200EP | - | SQJ200EP-T1_GE3 |
| SQJ202EP | - | SQJ202EP-T1_GE3 |
| SQJ401EP | SQJ401EP-T1-GE3 | SQJ401EP-T1_GE3 |
| SQJ402EP | SQJ402EP-T1-GE3 | SQJ402EP-T1_GE3 |
| SQJ403EEP | SQJ403EEP-T1-GE3 | SQJ403EEP-T1_GE3 |
| SQJ403EP | - | SQJ403EP-T1_GE3 |
| SQJ410EP | SQJ410EP-T1-GE3 | SQJ410EP-T1_GE3 |
| SQJ412EP | SQJ412EP-T1-GE3 | SQJ412EP-T1_GE3 |
| SQJ416EP | - | SQJ416EP-T1_GE3 |
| SQJ418EP | - | SQJ418EP-T1_GE3 |
| SQJ422EP | SQJ422EP-T1-GE3 | SQJ422EP-T1 GE3 |
| SQJ423EP | - | SQJ423EP-T1_GE3 |
| SQJ431EP | SQJ431EP-T1-GE3 | SQJ431EP-T1_GE3 |
| SQJ443EP | SQJ443EP-T1-GE3 | SQJ443EP-T1_GE3 |
| SQJ444EP | - | SQJ444EP-T1_GE3 |
| SQJ446EP | - | SQJ446EP-T1 GE3 |
| SQJ456EP | SQJ456EP-T1-GE3 | SQJ456EP-T1 GE3 |
| SQJ457EP | - | SQJ457EP-T1_GE3 |
| SQJ459EP | | SQJ459EP-T1_GE3 |
| SQJ460AEP | | SQJ460AEP-T1 GE3 |
| | SQJ461EP-T1-GE3 | SQJ461EP-T1 GE3 |
| SQJ461EP | SQJ463EP-T1-GE3 | |
| SQJ463EP | | SQJ463EP-T1_GE3 |
| SQJ465EP | SQJ465EP-T1-GE3 | SQJ465EP-T1_GE3 |
| SQJ469EP | SQJ469EP-T1-GE3 | SQJ469EP-T1_GE3 |
| SQJ474EP | <u>-</u> | SQJ474EP-T1_GE3 |
| SQJ476EP | - | SQJ476EP-T1_GE3 |
| SQJ479EP | - 00 H00ED T4 OF0 | SQJ479EP-T1_GE3 |
| SQJ486EP | SQJ486EP-T1-GE3 | SQJ486EP-T1_GE3 |
| SQJ488EP | SQJ488EP-T1-GE3 | SQJ488EP-T1_GE3 |
| SQJ500AEP | SQJ500AEP-T1-GE3 | SQJ500AEP-T1_GE3 |
| SQJ840EP | SQJ840EP-T1-GE3 | SQJ840EP-T1_GE3 |
| SQJ844AEP | SQJ844AEP-T1-GE3 | SQJ844AEP-T1_GE3 |
| SQJ850EP | SQJ850EP-T1-GE3 | SQJ850EP-T1_GE3 |
| SQJ858AEP | SQJ858AEP-T1-GE3 | SQJ858AEP-T1_GE3 |
| SQJ868EP | - | SQJ868EP-T1_GE3 |
| SQJ886EP | SQJ886EP-T1-GE3 | SQJ886EP-T1_GE3 |
| SQJ910AEP | SQJ910AEP-T1-GE3 | SQJ910AEP-T1_GE3 |
| SQJ912AEP | SQJ912AEP-T1-GE3 | SQJ912AEP-T1_GE3 |
| SQJ940EP | SQJ940EP-T1-GE3 | SQJ940EP-T1_GE3 |
| SQJ942EP | SQJ942EP-T1-GE3 | SQJ942EP-T1_GE3 |
| SQJ951EP | SQJ951EP-T1-GE3 | SQJ951EP-T1_GE3 |
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| SQJ956EP | SQJ956EP-T1-GE3 | SQJ956EP-T1_GE3 |
| SQJ960EP | SQJ960EP-T1-GE3 | SQJ960EP-T1_GE3 |
| SQJ963EP | SQJ963EP-T1-GE3 | SQJ963EP-T1_GE3 |
| SQJ968EP | SQJ968EP-T1-GE3 | SQJ968EP-T1_GE3 |
| SQJ980AEP | SQJ980AEP-T1-GE3 | SQJ980AEP-T1_GE3 |
| SQJ992EP | SQJ992EP-T1-GE3 | SQJ992EP-T1_GE3 |

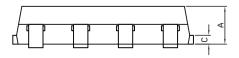
Note

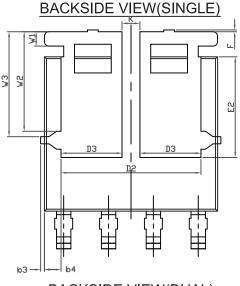
a. Old ordering code is obsolete and no longer valid for new orders

PowerPAK® SO-8L Case Outline for all Parts



TOPSIDE VIEW





BACKSIDE VIEW(DUAL)



| DIM | MILLIMETERS | | | INCHES | | |
|------|-------------|----------|----------------|-----------|-------|-------|
| DIM. | MIN. | NOM. | NOM. MAX. MIN. | | NOM. | MAX. |
| А | 1.00 | 1.07 | 1.14 | 0.039 | 0.042 | 0.045 |
| A1 | 0.00 | - | 0.127 | 0.00 | - | 0.005 |
| b | 0.33 | 0.41 | 0.48 | 0.013 | 0.016 | 0.019 |
| b1 | 0.44 | 0.51 | 0.58 | 0.017 | 0.020 | 0.023 |
| b2 | 4.80 | 4.90 | 5.00 | 0.189 | 0.193 | 0.197 |
| b3 | | 0.094 | | | 0.004 | |
| b4 | | 0.47 | | | 0.019 | |
| С | 0.20 | 0.25 | 0.30 | 0.008 | 0.010 | 0.012 |
| D | 5.00 | 5.13 | 5.25 | 0.197 | 0.202 | 0.207 |
| D1 | 4.80 | 4.90 | 5.00 | 0.189 | 0.193 | 0.197 |
| D2 | 3.86 | 3.96 | 4.06 | 0.152 | 0.156 | 0.160 |
| D3 | 1.63 | 1.73 | 1.83 | 0.064 | 0.068 | 0.072 |
| е | | 1.27 BSC | | 0.050 BSC | | |
| Е | 6.05 | 6.15 | 6.25 | 0.238 | 0.242 | 0.246 |
| E1 | 4.27 | 4.37 | 4.47 | 0.168 | 0.172 | 0.176 |
| E2 | 2.75 | 2.85 | 2.95 | 0.108 | 0.112 | 0.116 |
| F | - | - | 0.15 | - | - | 0.006 |
| L | 0.62 | 0.72 | 0.82 | 0.024 | 0.028 | 0.032 |
| L1 | 0.92 | 1.07 | 1.22 | 0.036 | 0.042 | 0.048 |
| K | | 0.51 | | | 0.020 | |
| W | 0.23 | | | 0.009 | | |
| W1 | 0.41 | | | 0.016 | | |
| W2 | 2.82 | | | 0.111 | | |
| W3 | | 2.96 | | | 0.117 | |
| q | 0° | - | 10° | 0° | _ | 10° |

ECN: C15-1203-Rev. A, 07-Sep-15

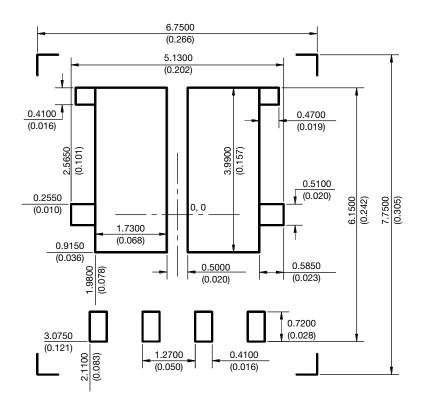
DWG: 6044

Note

· Millimeters will gover



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)



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Revision: 13-Jun-16 1 Document Number: 91000

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TPCC8103,L1Q(CM MIC4420CM-TR VN1206L 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C

IPS70R2K0CEAKMA1 BUK954R8-60E DMN3404LQ-7 NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI

DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE2384

NTE2903 NTE2941 NTE2945 NTE2946 NTE2960 NTE2967 NTE2969 NTE2976 NTE455 NTE6400A NTE2910 NTE2916 NTE2956

NTE2911 TK10A80W,S4X(S SSM6P69NU,LF DMP22D4UFO-7B